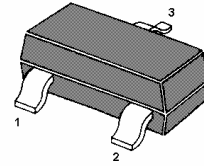


# MMBT9015

## PNP Silicon Epitaxial Planar Transistors

for switching and AF amplifier applications

As complementary types the NPN transistor MMBT9014 is recommended.



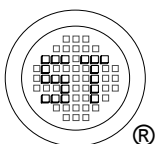
1.BASE 2.EMITTER 3.COLLECTOR  
SOT-23 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	50	V
Collector Emitter Voltage	$-V_{CEO}$	45	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current	$-I_C$	100	mA
Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_s$	- 55 to + 150	$^\circ\text{C}$

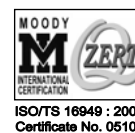
### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE} = 5\text{ V}$ , $-I_C = 1\text{ mA}$	MMBT9015B $h_{FE}$	125	250	-
	MMBT9015C $h_{FE}$	220	475	-
	MMBT9015D $h_{FE}$	420	800	-
Collector Cutoff Current at $-V_{CB} = 50\text{ V}$	$-I_{CBO}$	-	50	nA
Emitter Cutoff Current at $-V_{EB} = 5\text{ V}$	$-I_{EBO}$	-	50	nA
Collector Base Breakdown Voltage at $-I_C = 100\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	50	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	45	-	V
Emitter Base Breakdown Voltage at $-I_E = 100\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	5	-	V
Collector Emitter Saturation Voltage at $-I_C = 100\text{ mA}$ , $-I_B = 5\text{ mA}$	$-V_{CE(sat)}$	-	0.65	V
Base Emitter Saturation Voltage at $-I_C = 100\text{ mA}$ , $-I_B = 5\text{ mA}$	$-V_{BE(sat)}$	-	1	V
Gain Bandwidth Product at $-V_{CE} = 5\text{ V}$ , $-I_C = 10\text{ mA}$	$f_T$	100	-	MHz
Output Capacitance at $-V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{OB}$	-	7	pF
Noise Figure at $-V_{CE} = 5\text{ V}$ , $-I_C = 200\text{ }\mu\text{A}$ , $f = 1\text{ KHz}$ , $R_G = 2\text{ K}\Omega$	NF	-	10	dB



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Dated : 13/08/2007

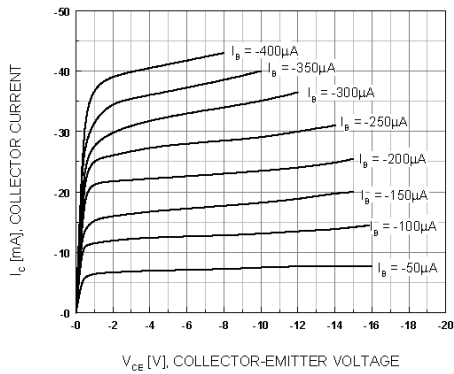


Figure 1. Static Characteristic

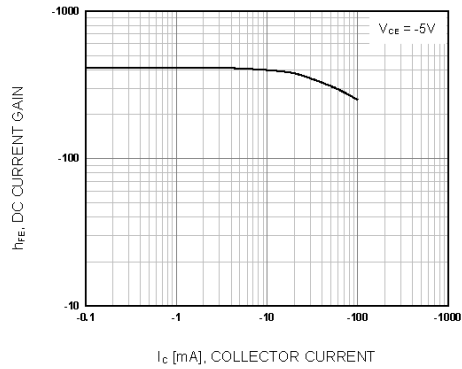


Figure 2. DC current Gain

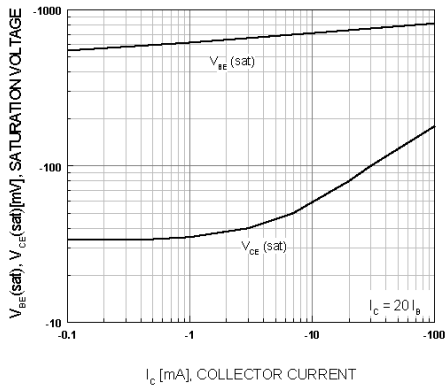


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

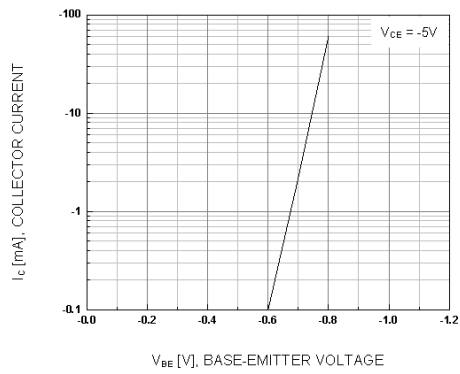


Figure 4. Base-Emitter On Voltage

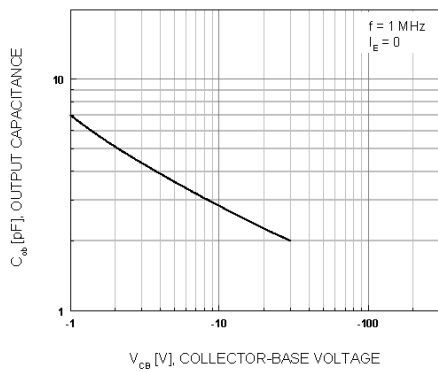


Figure 5. Collector Output Capacitance

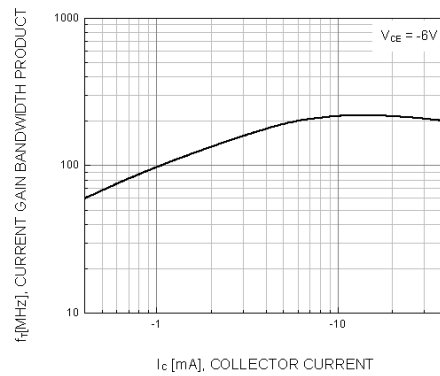
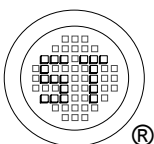


Figure 6. Current Gain Bandwidth Product



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